

isc Silicon PNP Power Transistor

2SB1163

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -180V(Min)
- Good Linearity of hFE
- Wide Area of Safe Operation
- Complement to Type 2SD1718
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

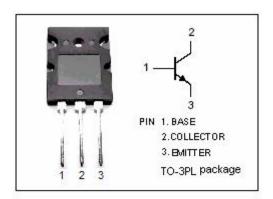


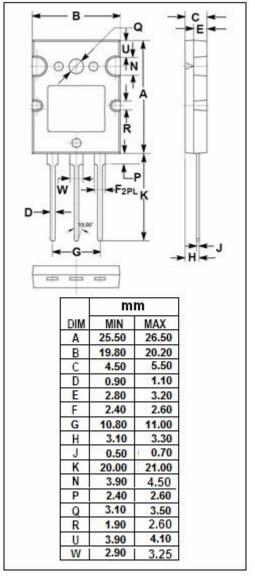
APPLICATIONS

Designed for high power amplifier applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-180	V	
Vceo	Collector-Emitter Voltage	-180	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-15	Α	
I _{CP}	Collector Current-Pulse	-25	Α	
Pc	Collector Power Dissipation @ $T_C=25^{\circ}C$	150	W	
	Collector Power Dissipation @ T _a =25 ℃	3.5		
TJ	Junction Temperature 150		$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







isc Silicon PNP Power Transistor

2SB1163

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10A; I _B = -1A			-2.5	V
V _{BE(on)}	Base -Emitter On Voltage	I _C = -8A; V _{CE} = -5V			-1.8	V
Ісво	Collector Cutoff Current	V _{CB} = -180V; I _E = 0			-50	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = -3V; I _C = 0			-50	μА
h _{FE-1}	DC Current Gain	I _C = -20mA; V _{CE} = -5V	20			
h _{FE-2}	DC Current Gain	I _C = -1A; V _{CE} = -5V	60		200	
h _{FE-3}	DC Current Gain	I _C = -8A; V _{CE} = -5V	20			
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f _{test} = 1.0MHz		230		pF
f⊤	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -5V		20		MHz

♦ h_{FE-2} Classifications

Q	S	Р
60-120	80-160	100-200

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.